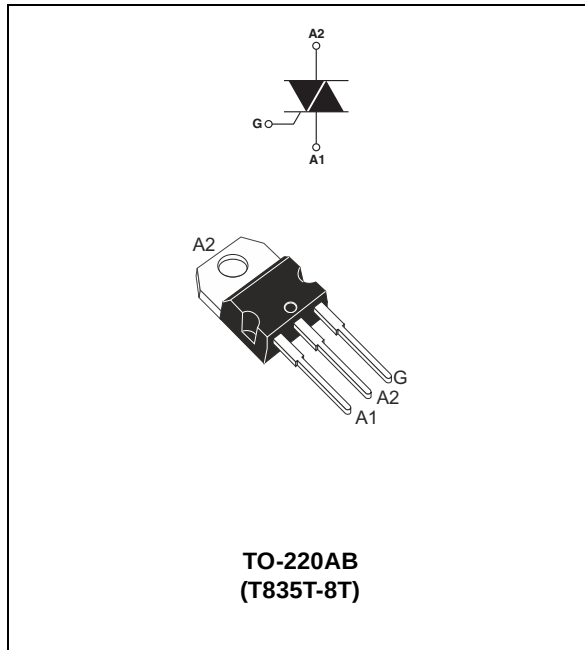


## 8 A Snubberless™ Triac

Datasheet — production data



**Table 1. Device summary**

| Symbol             | Value | Unit |
|--------------------|-------|------|
| $I_{T(rms)}$       | 8     | A    |
| $V_{DRM}, V_{RRM}$ | 800   | V    |
| $V_{DSM}, V_{RSM}$ | 900   | V    |
| $I_{GT}$           | 35    | mA   |

### Features

- Medium current Triac
- High static and dynamic commutation
- Three quadrants
- ECOPACK®2 compliant component

### Applications

- General purpose AC line load switching
- Motor control circuits
- Small home appliances
- Lighting
- Inrush current limiting circuits
- Overvoltage crowbar protection

### Description

Available in through-hole package, the T835T-8T Triac can be used for the on/off or phase angle control function in general purpose AC switching where high commutation capability is required. This device can be used without a snubber circuit when the limits defined in this datasheet are respected

TM: Snubberless is a trademark of STMicroelectronics

# 1 Characteristics

**Table 2. Absolute maximum ratings ( $T_j = 25\text{ °C}$  unless otherwise stated)**

| Symbol             | Parameter                                                                                    |                         |                       | Value         | Unit        |
|--------------------|----------------------------------------------------------------------------------------------|-------------------------|-----------------------|---------------|-------------|
| $I_{T(rms)}$       | On-state rms current (full sine wave)                                                        |                         | $T_c = 131\text{ °C}$ | 8             | A           |
| $I_{TSM}$          | Non repetitive surge peak on-state current (full cycle, $T_j$ initial = $25\text{ °C}$ )     | $F = 50\text{ Hz}$      | $t = 20\text{ ms}$    | 60            | A           |
|                    |                                                                                              | $F = 60\text{ Hz}$      | $t = 16.7\text{ ms}$  | 63            |             |
| $I^2t$             | $I^2t$ value for fusing, $T_j$ initial = $25\text{ °C}$                                      |                         | $t_p = 10\text{ ms}$  | 24            | $A^2s$      |
| $V_{DRM}, V_{RRM}$ | Repetitive surge peak off-state voltage                                                      |                         | $T_j = 150\text{ °C}$ | 600           | V           |
|                    |                                                                                              |                         | $T_j = 125\text{ °C}$ | 800           |             |
| $V_{DSM}, V_{RSM}$ | Non repetitive surge peak off-state voltage                                                  |                         | $t_p = 10\text{ ms}$  | 900           | V           |
| $di/dt$            | Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \leq 100\text{ ns}$ | $F = 100\text{ Hz}$     |                       | 100           | $A/\mu s$   |
| $I_{GM}$           | Peak gate current                                                                            | $t_p = 20\text{ }\mu s$ | $T_j = 150\text{ °C}$ | 4             | A           |
| $P_{G(AV)}$        | Average gate power dissipation                                                               |                         | $T_j = 150\text{ °C}$ | 1             | W           |
| $T_{stg}$          | Storage junction temperature range                                                           |                         |                       | - 40 to + 150 | $^{\circ}C$ |
| $T_j$              | Operating junction temperature range                                                         |                         |                       | - 40 to + 150 |             |
| $T_L$              | Maximum lead temperature for soldering during 10 s                                           |                         |                       | 260           | $^{\circ}C$ |

**Table 3. Electrical characteristics ( $T_j = 25\text{ °C}$ , unless otherwise stated)**

| Symbol            | Test conditions                                                      | Quadrant              |      | Value | Unit      |
|-------------------|----------------------------------------------------------------------|-----------------------|------|-------|-----------|
| $I_{GT}^{(1)}$    | $V_D = 12\text{ V}$ , $R_L = 30\text{ }\Omega$                       | I - II - III          | Min. | 1.75  | mA        |
|                   |                                                                      |                       | Max. | 35    |           |
| $V_{GT}$          | $V_D = 12\text{ V}$ , $R_L = 30\text{ }\Omega$                       | I - II - III          | Max. | 1.3   | V         |
| $V_{GD}$          | $V_D = V_{DRM}$ , $R_L = 3.3\text{ k}\Omega$ , $T_j = 150\text{ °C}$ | I - II - III          | Min. | 0.2   | V         |
| $I_H^{(1)}$       | $I_T = 500\text{ mA}$                                                |                       | Max. | 40    | mA        |
| $I_L$             | $I_G = 1.2 I_{GT}$                                                   | I - III               | Max. | 60    | mA        |
|                   |                                                                      | II                    | Max. | 65    | mA        |
| $dV/dt^{(1)}$     | $V_D = 536\text{ V}$ , gate open                                     | $T_j = 125\text{ °C}$ | Min. | 2000  | $V/\mu s$ |
|                   | $V_D = 402\text{ V}$ , gate open                                     | $T_j = 150\text{ °C}$ |      | 1000  | $V/\mu s$ |
| $(di/dt)_C^{(1)}$ | Without snubber ( $dV/dt)_C \geq 20\text{ V}/\mu s$ )                | $T_j = 125\text{ °C}$ | Min. | 8     | A/ms      |
|                   |                                                                      | $T_j = 150\text{ °C}$ |      | 4     |           |

1. For both polarities of A2 referenced to A1

Table 4. Static Characteristics

| Symbol                 | Test conditions                                     |                                    |      | Value | Unit          |
|------------------------|-----------------------------------------------------|------------------------------------|------|-------|---------------|
| $V_T^{(1)}$            | $I_{TM} = 11.3 \text{ A}$ , $t_p = 380 \mu\text{s}$ | $T_j = 25 \text{ }^\circ\text{C}$  | Max. | 1.55  | V             |
| $V_{t0}^{(1)}$         | Threshold voltage                                   | $T_j = 150 \text{ }^\circ\text{C}$ | Max. | 0.85  | V             |
| $R_d^{(1)}$            | Dynamic resistance                                  | $T_j = 150 \text{ }^\circ\text{C}$ | Max. | 57    | m $\Omega$    |
| $I_{DRM}$<br>$I_{RRM}$ | $V_{DRM} = V_{RRM} = 800 \text{ V}$                 | $T_j = 25 \text{ }^\circ\text{C}$  | Max. | 5     | $\mu\text{A}$ |
|                        |                                                     | $T_j = 125 \text{ }^\circ\text{C}$ |      | 0.8   | mA            |
|                        | $V_{DRM} = V_{RRM} = 600 \text{ V}$                 | $T_j = 150 \text{ }^\circ\text{C}$ | Max. | 2.4   |               |

1. For both polarities of A2 referenced to A1

Table 5. Thermal resistance

| Symbol        | Parameter             | Value | Unit               |
|---------------|-----------------------|-------|--------------------|
| $R_{th(j-c)}$ | Junction to case (AC) | 1.9   | $^\circ\text{C/W}$ |
| $R_{th(j-a)}$ | Junction to ambient   | 60    | $^\circ\text{C/W}$ |

Figure 1. Maximum power dissipation versus on-state rms current (full cycle)

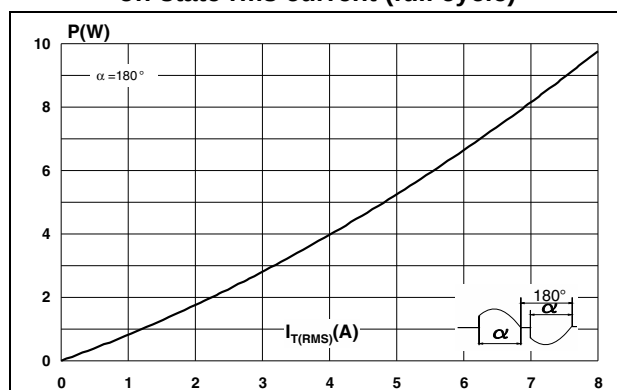


Figure 2. On-state rms current versus case temperature (full cycle)

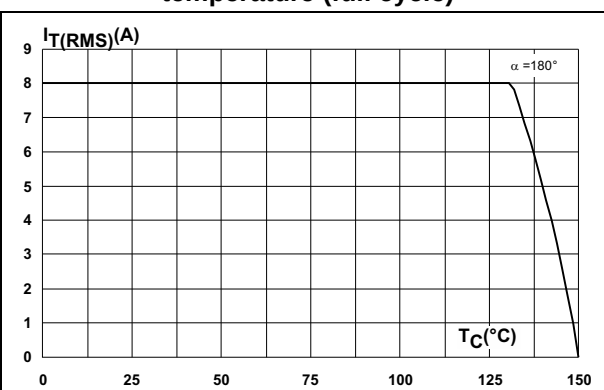


Figure 3. On-state rms current versus ambient temperature (free air convection)

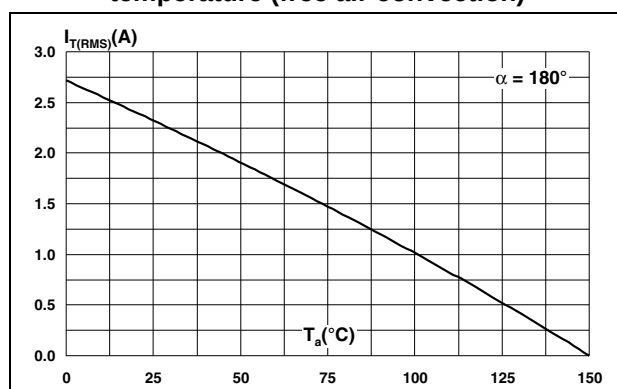


Figure 4. Relative variation of thermal impedance versus pulse duration

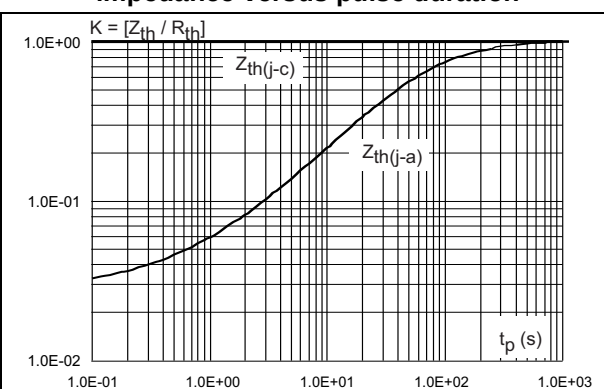


Figure 5. On-state characteristics (maximum values)

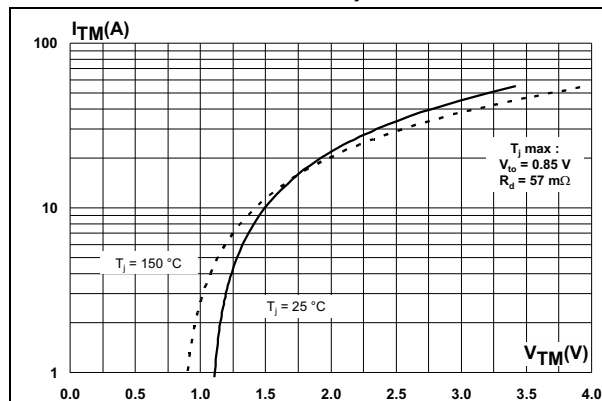


Figure 6. Surge peak on-state current versus number of cycles

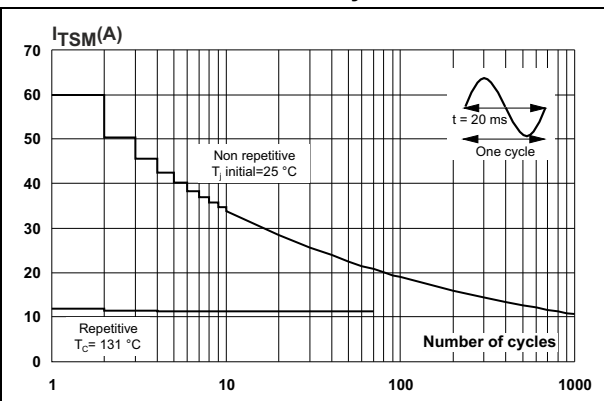
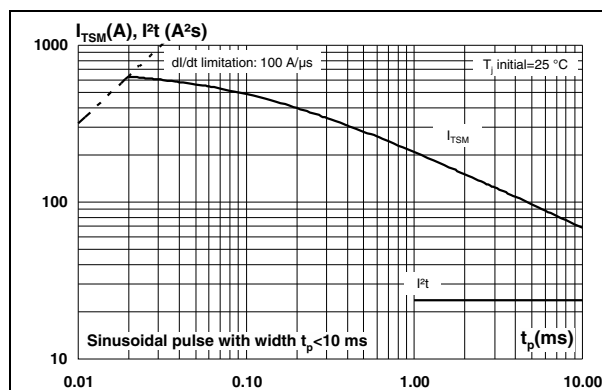
Figure 7. Non repetitive surge peak on-state current and corresponding values of  $I^2t$ 

Figure 8. Relative variation of gate trigger current and gate voltage versus junction temperature (typical values)

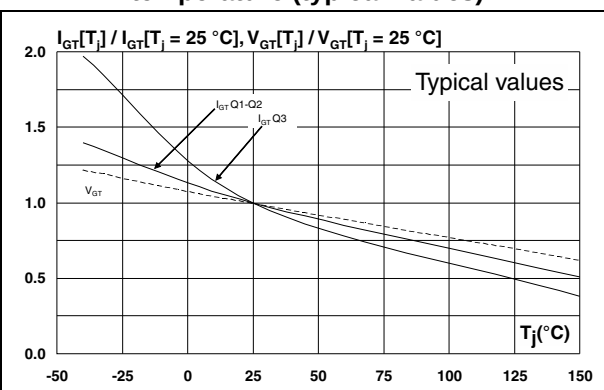


Figure 9. Relative variation of static dV/dt immunity versus junction temperature (typical values)

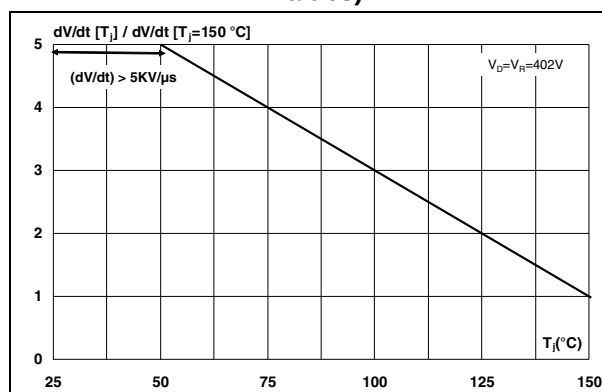
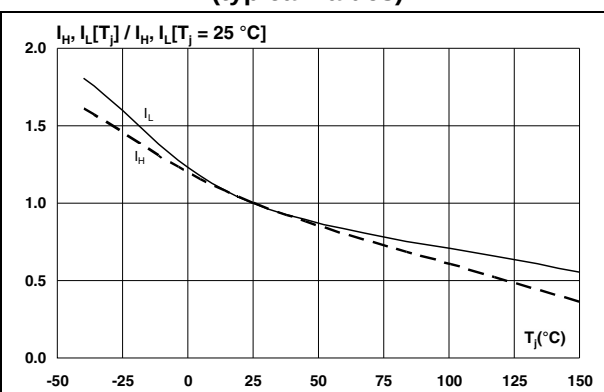
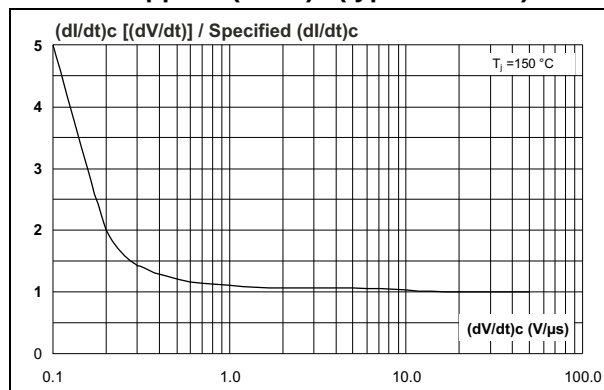


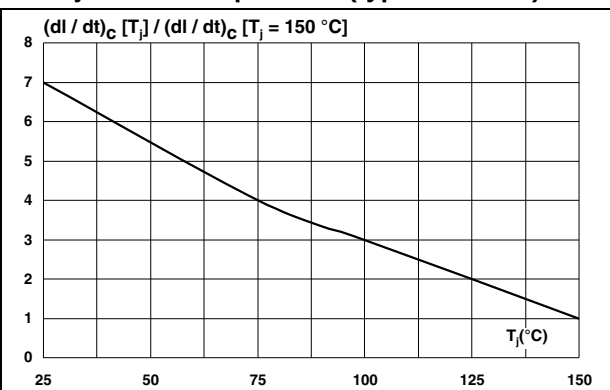
Figure 10. Relative variation of holding and latching current versus junction temperature (typical values)



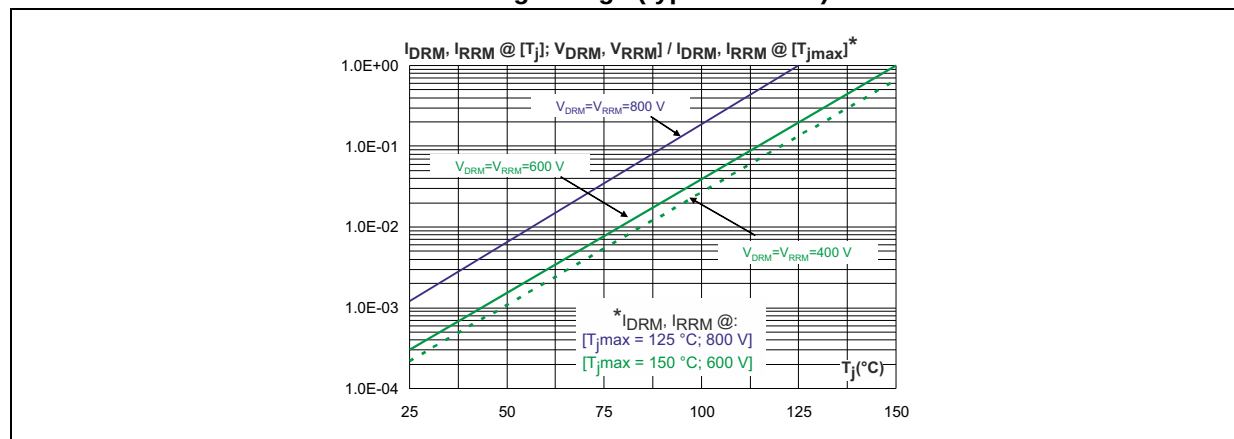
**Figure 11. Relative variation of critical rate of decrease of main current  $(di/dt)_c$  versus reapplied  $(dV/dt)_c$  (typical values)**



**Figure 12. Relative variation of critical rate of decrease of main current  $(di/dt)_c$  versus junction temperature (typical values)**



**Figure 13. Relative variation of leakage current versus junction temperature for different values of blocking voltage (typical values)**



## 2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

**Figure 14. TO-220AB dimension definitions**

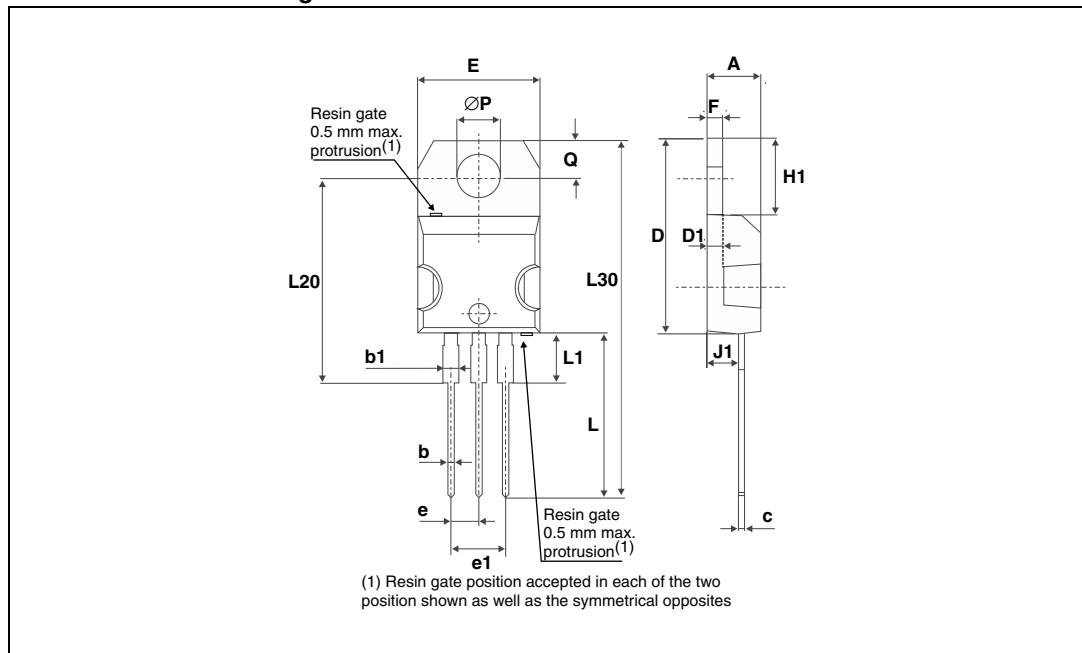


Table 6. TO-220AB dimension values

| Ref. | Dimensions  |       |           |       |
|------|-------------|-------|-----------|-------|
|      | Millimeters |       | Inches    |       |
|      | Min.        | Max.  | Min.      | Max.  |
| A    | 4.40        | 4.60  | 0.17      | 0.18  |
| b    | 0.61        | 0.88  | 0.024     | 0.035 |
| b1   | 1.14        | 1.70  | 0.045     | 0.067 |
| c    | 0.48        | 0.70  | 0.019     | 0.027 |
| D    | 15.25       | 15.75 | 0.60      | 0.62  |
| D1   | 1.27 typ.   |       | 0.05 typ. |       |
| E    | 10          | 10.40 | 0.39      | 0.41  |
| e    | 2.40        | 2.70  | 0.094     | 0.106 |
| e1   | 4.95        | 5.15  | 0.19      | 0.20  |
| F    | 1.23        | 1.32  | 0.048     | 0.052 |
| H1   | 6.20        | 6.60  | 0.24      | 0.26  |
| J1   | 2.40        | 2.72  | 0.094     | 0.107 |
| L    | 13          | 14    | 0.51      | 0.55  |
| L1   | 3.50        | 3.93  | 0.137     | 0.154 |
| L20  | 16.40 typ.  |       | 0.64 typ. |       |
| L30  | 28.90 typ.  |       | 1.13 typ. |       |
| ØP   | 3.75        | 3.85  | 0.147     | 0.151 |
| Q    | 2.65        | 2.95  | 0.104     | 0.116 |

### 3 Ordering information

Figure 15. Ordering information scheme

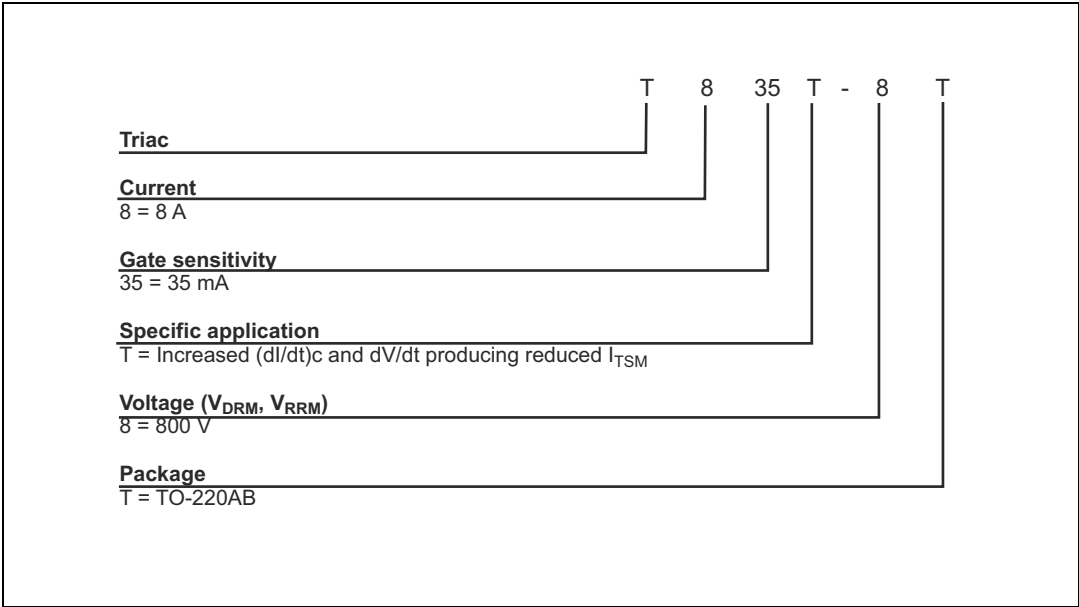


Table 7. Ordering information

| Order code | Marking  | Package  | Weight | Base qty | Delivery mode |
|------------|----------|----------|--------|----------|---------------|
| T835T-8T   | T835T-8T | TO-220AB | 2.0 g  | 50       | Tube          |

### 4 Revision history

Table 8. Document revision history

| Date        | Revision | Changes                           |
|-------------|----------|-----------------------------------|
| 05-Aug-2013 | 1        | Initial release.                  |
| 01-Jul-2014 | 2        | Updated <a href="#">Table 2</a> . |
| 28-Jul-2014 | 3        | Updated <a href="#">Table 5</a> . |

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